Quad 2-Input Exclusive OR Gate

MM74HC86

The MM74HC86 exclusive OR gate utilizes advanced silicon−gate CMOS technology to achieve operating speeds similar to equivalent LS−TTL gates, while maintaining the low power consumption and high noise immunity characteristic of standard CMOS integrated circuits. These gates are fully buffered and have a fanout of 10 LS−TTL loads. The 74HC logic family is functionally as well as pin−out compatible with the standard 74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical Propagation Delay: 12 ns
- Wide Operating Voltage Range: 2 V – 6 V
- Low Input Current: 1 μA Maximum
- Low Quiescent Current: 40 μA Maximum (74 Series)
- Output Drive Capability: 10 LS−TTL Loads
- These Devices are Pb−Free, Halide Free and are RoHS Compliant

Connection Diagram

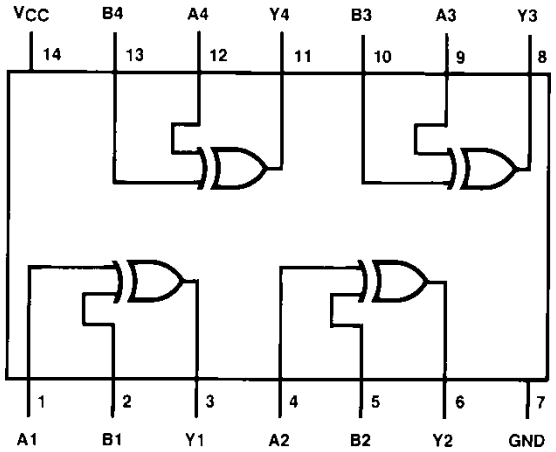
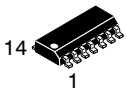


Figure 1. Pin Assignments (Top View)

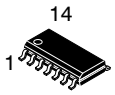
TRUTH TABLE

Inputs		Outputs
A	**B**	**Y** (Note1)
L	L	L
L	H	H
H	L	H
H	H	L

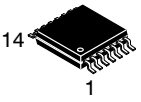
1. $Y = A \oplus B = \overline{A}B + A\overline{B}$



SOIC−14
CASE 751A−03

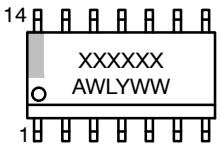


SOIC−14
CASE 751EF

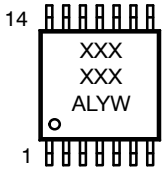


TSSOP−14
CASE 948G

MARKING DIAGRAM



SOIC−14



TSSOP−14 WB

XXX = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
Y = Year
WW, W = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

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MAXIMUM RATINGS

Symbol	Parameter		Min	Max	Unit
V_{CC}	Supply Voltage		−0.5	6.5	V
V_{IN}	DC Input Voltage		−0.5	V_{CC} + 0.5	V
V_{OUT}	DC Output Voltage		−0.5	V_{CC} + 0.5	V
I_{IK}, I_{OK}	Clamp Diode Current		±20		mA
I_{OUT}	DC Output Current, per Pin		±25		mA
I_{CC}	DC V_{CC} or GND Current, per Pin		±50		mA
T_{STG}	Storage Temperature Range		−65	+150	°C
T_L	Lead Temperature (Soldering, 10 Seconds)		–	260	°C
P_D	Power Dissipation	SOIC	–	1077	mW
		TSSOP	–	833	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	Supply Voltage		2	6	V
V_{IN}, V_{OUT}	DC Input or Output Voltage		0	V_{CC}	V
T_A	Operating Temperature Range		−55	+125	°C
t_r, t_f	Input Rise or Fall Times	V_{CC} = 2.0 V	–	1000	ns
		V_{CC} = 4.5 V	–	500	
		V_{CC} = 6.0 V	–	400	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

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DC CHARACTERISTICS (Note 2)

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C	T_A = −40°C to 85°C	T_A = −55°C to 125°C	Unit
				Typ	Guaranteed Limits		
V_{IH}	Minimum HIGH Level Input Voltage		2.0	–	1.5	1.5	1.5	V
			4.5	–	3.15	3.15	3.15	
			6.0	–	4.2	4.2	4.2	
V_{IL}	Maximum LOW Level Input Voltage		2.0	–	0.5	0.5	0.5	V
			4.5	–	1.35	1.35	1.35	
			6.0	–	1.8	1.8	1.8	
V_{OH}	Minimum HIGH Level Output Voltage	V_{IN} = V_{IH} or V_{IL}, $\|I_{OUT}\| \le 20$ μA	2.0	2.0	1.9	1.9	1.9	V
			4.5	4.5	4.4	4.4	4.4	
			6.0	6.0	5.9	5.9	5.9	
		V_{IN} = V_{IH} or V_{IL}, $\|I_{OUT}\| \le 4.0$ mA	4.5	4.2	3.98	3.84	3.70	
		V_{IN} = V_{IH} or V_{IL}, $\|I_{OUT}\| \le 5.2$ mA	6.0	5.7	5.48	5.34	5.20	
V_{OL}	Maximum LOW Level Output Voltage	V_{IN} = V_{IH} or V_{IL}, $\|I_{OUT}\| \le 20$ μA	2.0	0	0.1	0.1	0.1	V
			4.5	0	0.1	0.1	0.1	
			6.0	0	0.1	0.1	0.1	
		V_{IN} = V_{IH} or V_{IL}, $\|I_{OUT}\| \le 4.0$ mA	4.5	0.2	0.26	0.33	0.4	
		V_{IN} = V_{IH} or V_{IL}, $\|I_{OUT}\| \le 5.2$ mA	6.0	0.2	0.26	0.33	0.4	
I_{IN}	Maximum Input Current	V_{IN} = V_{CC} or GND	6.0	–	±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current	V_{IN} = V_{CC} or GND, I_{OUT} = 0 mA	6.0	–	2.0	20	40	μA

2. For a power supply of 5 V ±10% the worst−case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5 V. Thus the 4.5 V values should be used when designing with this supply. Worst−case V_{IH} and V_{IL} occur at V_{CC} = 5.5 V and 4.5 V, respectively. (The V_{IH} values at 5 V and 5.5 V are 3.5 V and 3.85 V, respectively.) The worst−case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occurs for CMOS at the higher voltage, so the 6.0 V values should be used.

AC CHARACTERISTICS (C_L = 50 pF, t_r = t_f = 6 ns (unless otherwise specified))

Symbol	Parameter	Conditions	V_{CC} (V)	T_A = 25°C	T_A = −40°C to 85°C	T_A = −55°C to 125°C	Unit
				Typ	Guaranteed Limits		
t_{PHL}, t_{PLH}	Maximum Propagation Delay	C_L = 15 pF, t_R = t_F = 6 ns	5.0	12	–	20	–	ns
t_{PHL}, t_{PLH}	Maximum Propagation Delay	C_L = 50 pF, t_R = t_F = 6 ns	2.0	60	120	151	179	ns
			4.5	12	24	30	36	
			6.0	10	20	26	30	
t_{TLH}, t_{THL}	Maximum Output Rise and Fall Time		2.0	30	75	95	110	ns
			4.5	8	15	19	22	
			6.0	7	13	16	19	
C_{PD}	Power Dissipation Capacitance (per Gate) (Note 3)			25	–	–	–	pF
C_{IN}	Maximum Input Capacitance			5	10	10	10	pF

3. C_{PD} determines the no−load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

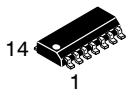
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ORDERING INFORMATION

Part Number	Marking	Package	Shipping†
MM74HC86M	HC86A	SOIC−14, Case 751A−03 (Pb−Free, Halide Free)	55 Units / Tube
MM74HC86MTC	HC 86A	TSSOP−14, Case 948G−01 (Pb−Free, Halide Free)	96 Units / Tube
MM74HC86MX	HC86A	SOIC−14, Case 751EF (Pb−Free, Halide Free)	2500 / Tape & Reel
MM74HC86MTCX	HC 86A	TSSOP−14, Case 948G−01 (Pb−Free, Halide Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

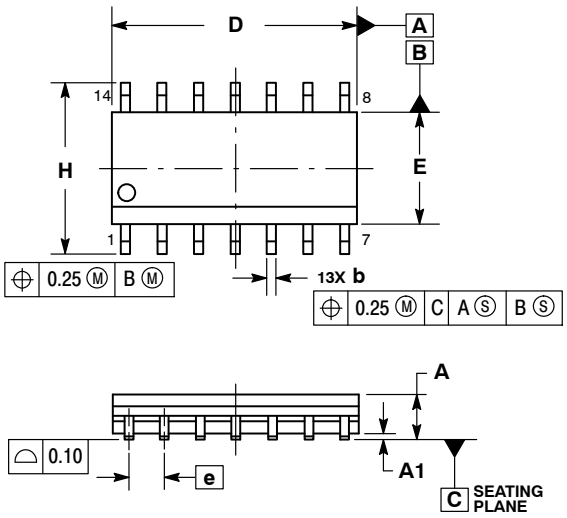
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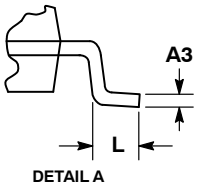


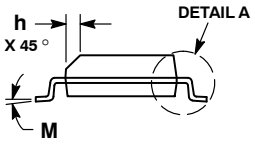
SCALE 1:1

SOIC−14 NB
CASE 751A−03
ISSUE L

DATE 03 FEB 2016



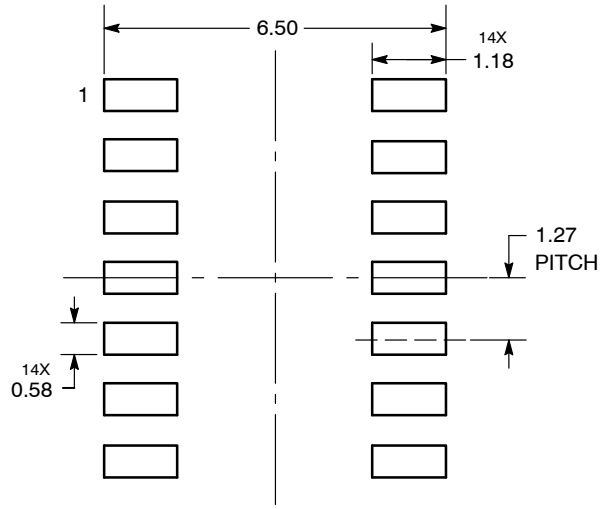




NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0 °	7 °	0 °	7 °

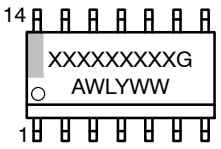
SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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SOIC−14
CASE 751A−03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 2:
CANCELLED

STYLE 3:
PIN 1. NO CONNECTION
2. ANODE
3. ANODE
4. NO CONNECTION
5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

STYLE 4:
PIN 1. NO CONNECTION
2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
8. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 5:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 6:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
2. COMMON ANODE
3. COMMON CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. ANODE/CATHODE
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. COMMON CATHODE
12. COMMON ANODE
13. ANODE/CATHODE
14. ANODE/CATHODE

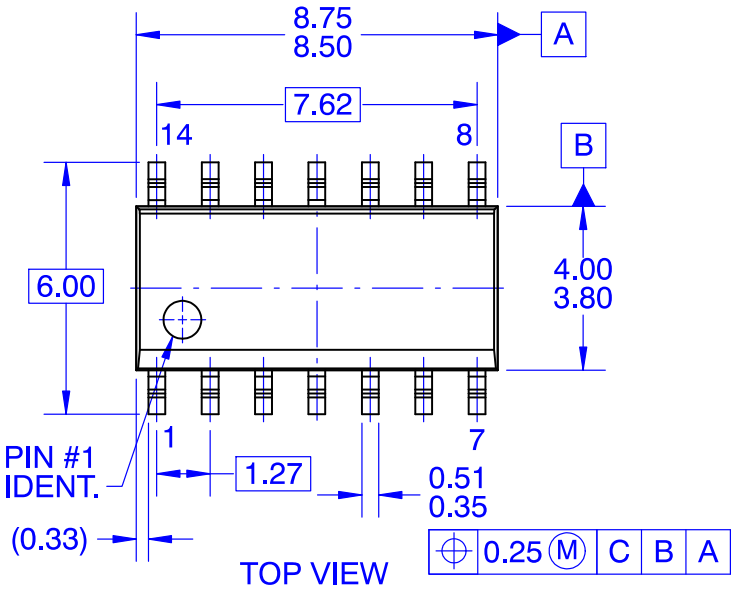
STYLE 8:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE

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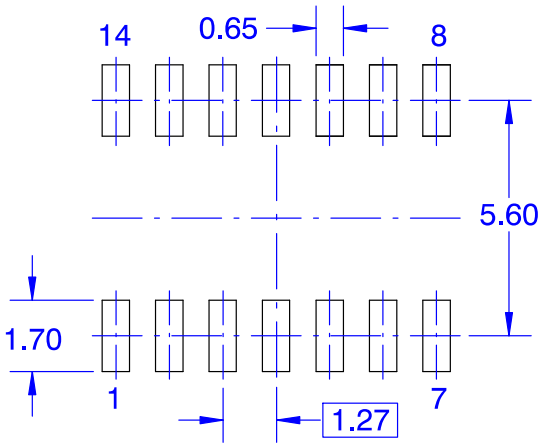
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SOIC14
CASE 751EF
ISSUE O

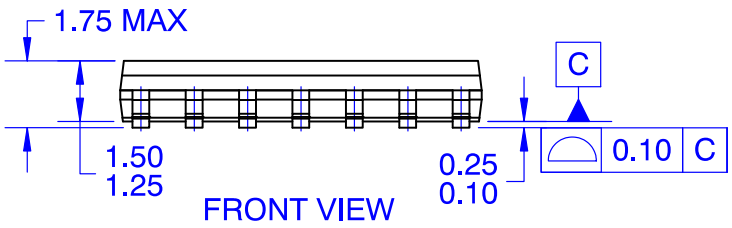
DATE 30 SEP 2016



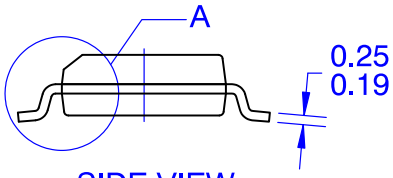
TOP VIEW



LAND PATTERN RECOMMENDATION

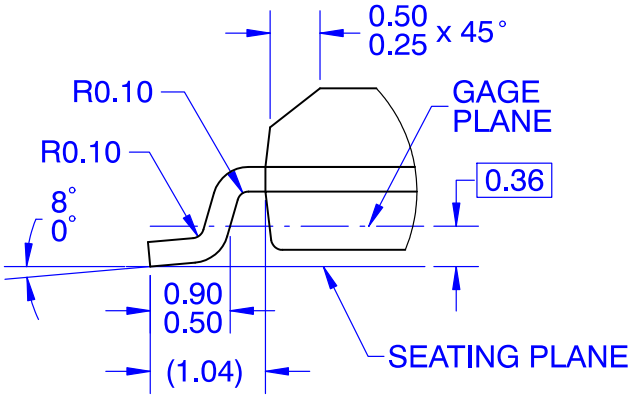


FRONT VIEW



SIDE VIEW

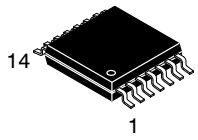
NOTES:
A. CONFORMS TO JEDEC MS−012, VARIATION AB, ISSUE C
B. ALL DIMENSIONS ARE IN MILLIMETERS
C. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS
D. LAND PATTERN STANDARD: SOIC127P600X145−14M
E. CONFORMS TO ASME Y14.5M, 2009



DETAIL A
SCALE 16 : 1

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DESCRIPTION:	**SOIC14**	**PAGE 1 OF 1**

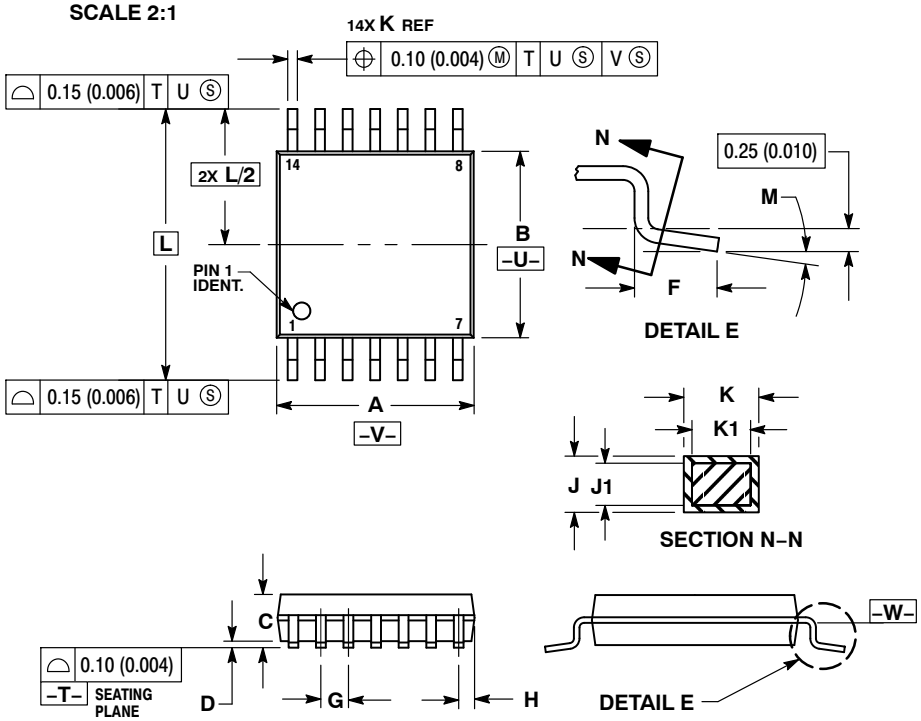
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SCALE 2:1

TSSOP−14 WB
CASE 948G
ISSUE C

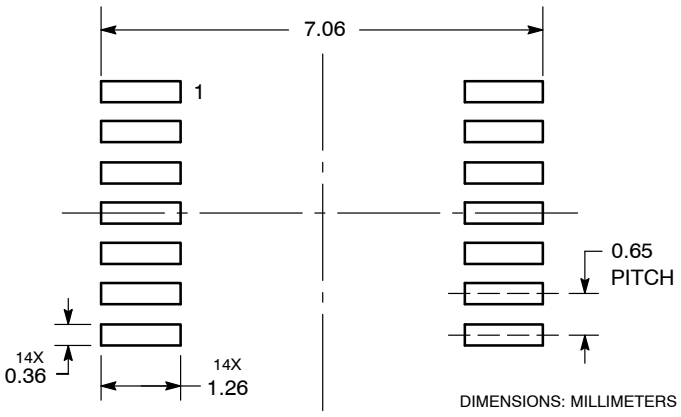
DATE 17 FEB 2016



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

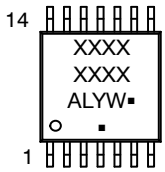
	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	−−−	1.20	−−−	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



A	= Assembly Location
L	= Wafer Lot
Y	= Year
W	= Work Week
▪	= Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**TSSOP−14 WB**	**PAGE 1 OF 1**

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